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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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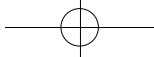
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# 2 $\phi$ 5 $\times$ 7 Single Color Dot Matrix LED Displays

LTP-747 Series  
757

## Features

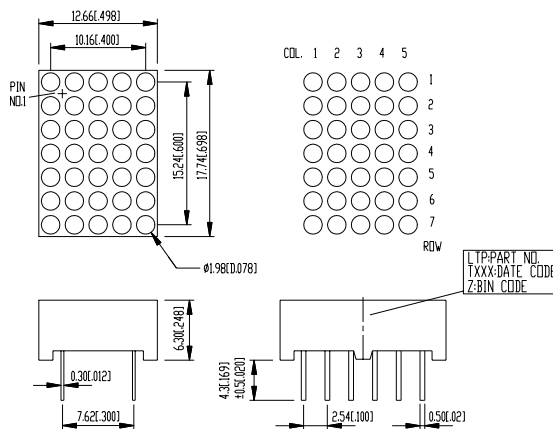
- 0.7 inch (17.22mm) matrix height
- Choices of four bright colors-green/yellow/red orange/AlGaAs red.
- Low power requirement.
- 5  $\times$  7 array with X-Y select.
- Compatible with usascII and ebcidc codes.
- Stackable vertically and horizontally.
- Choices of two matrix orientation.  
Cathode row, or cathode column.
- Easy mounting on P.C. board or sockets.
- Categorized for luminous intensity.

## Description

The LTP-747/757 series are 0.7 inch (17.2mm) matrix height 5  $\times$  7 dot matrix displays. The green, yellow, red orange and AlGaAs red displays have gray face and white dots.

The AlGaAs red series devices utilize LED chips which are made from AlGaAs on a non-transparent GaAs substrate. The green series devices utilize LED chips which are made from GaP on a transparent GaP substrate. The yellow and red orange series utilize LED chips which are made from GaAsP on a transparent GaP substrate.

## Package Dimensions



Notes : All dimensions are in millimeters(inches).  
Tolerance :  $\pm 0.25\text{mm}$  (0.010") unless otherwise noted.

DISPLAYS

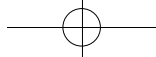
## Devices

Part No.				Description	Internal Circuit Diagram
Green	Yellow	Red Orange	AlGaAs Red		
LTP-747G	LTP-747Y	LTP-747E	LTP-747C	Anode Column, Cathode Row	A
LTP-757G	LTP-757Y	LTP-757E	LTP-757C	Cathode Column, Anode Row	B

## Pin Connection

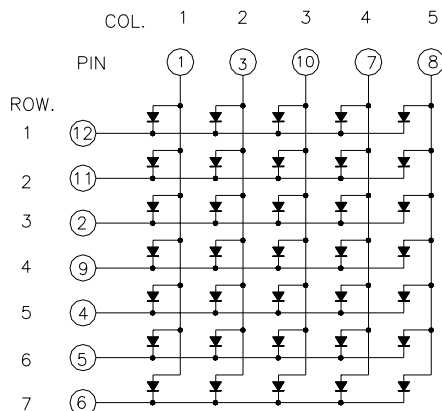
Pin No.	Connection	
	LTP-747	LTP-757
1	Anode Column 1	Cathode Column 1
2	Cathode Row 3	Anode Row 3
3	Anode Column 2	Cathode Column 2
4	Cathode Row 5	Anode Row 5
5	Cathode Row 6	Anode Row 6
6	Cathode Row 7	Anode Row 7
7	Anode Column 4	Cathode Column 4
8	Anode Column 5	Cathode Column 5
9	Cathode Row 4	Anode Row 4
10	Anode Column 3	Cathode Column 3
11	Cathode Row 2	Anode Row 2
12	Cathode Row 1	Anode Row 1

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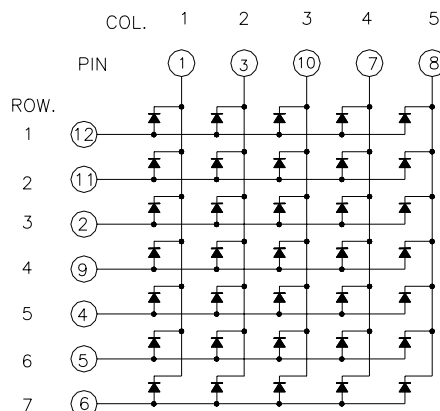


## Internal Circuit Diagrams

A. LTP-747



B. LTP-757



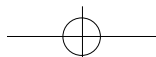
## Absolute Maximum Ratings at Ta=25°C

Parameter	Green	Yellow	Red Orange	AlGaAs Red	Unit
Average Power Dissipation Per Dot	32	28	32	32	mW
Peak Forward Current Per Dot (1/10 Duty Cycle, 0.1ms Pulse Width)	90	80	90	110	mA
Average Forward Current Per Dot Derating Linear from 25°C Per Dot	11 0.15	8 0.11	11 0.15	14 0.19	mA mA/°C
Reverse Voltage Per Dot	5	5	5	5	V
Operating Temperature Range	-35°C to +85°C				
Storage Temperature Range	-35°C to +85°C				
Solder Temperature 1/16 Inch Below Seating Plane for 3 Seconds at 260°C					

## Electrical/Optical Characteristics at Ta=25°C

LTP-747G/757G

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Average Luminous Intensity	I <sub>v</sub>	630	2000		μ cd	I <sub>F</sub> =80mA 1/16 Duty
Peak Emission Wavelength	λ <sub>P</sub>		565		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		30		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		569		nm	I <sub>F</sub> =20mA
Forward Voltage, any Dot	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
			3.0	3.7	V	I <sub>F</sub> =80mA
Reverse Current, any Dot	I <sub>R</sub>			100	μ A	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =80mA 1/16 Duty





LTP-747Y/757Y

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Average Luminous Intensity	I <sub>v</sub>	630	2000		μ cd	I <sub>F</sub> =80mA 1/16 Duty
Peak Emission Wavelength	λ <sub>P</sub>		585		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		35		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		588		nm	I <sub>F</sub> =20mA
Forward Voltage, any Dot	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
			3.0	3.7	V	I <sub>F</sub> =80mA
Reverse Current, any Dot	I <sub>R</sub>			100	μ A	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =80mA 1/16 Duty

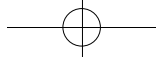
LTP-747E/757E

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Average Luminous Intensity	I <sub>v</sub>	630	2000		μ cd	I <sub>F</sub> =80mA 1/16 Duty
Peak Emission Wavelength	λ <sub>P</sub>		630		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		40		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		621		nm	I <sub>F</sub> =20mA
Forward Voltage, any Dot	V <sub>F</sub>		2.0	2.6	V	I <sub>F</sub> =20mA
			2.6	3.4	V	I <sub>F</sub> =80mA
Reverse Current, any Dot	I <sub>R</sub>			100	μ A	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =80mA 1/16 Duty

LTP-747C/757C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Average Luminous Intensity	I <sub>v</sub>	5000	9000		μ cd	I <sub>F</sub> =80mA 1/16 Duty
Peak Emission Wavelength	λ <sub>P</sub>		660		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		35		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		638		nm	I <sub>F</sub> =20mA
Forward Voltage, any Dot	V <sub>F</sub>		1.8	2.4	V	I <sub>F</sub> =20mA
			2.0	3.1	V	I <sub>F</sub> =80mA
Reverse Current, any Dot	I <sub>R</sub>			100	μ A	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>F</sub> =80mA 1/16 Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commission Internationale De L'Eclairage) eye-response curve.



## Typical Electrical/Optical Characteristic Curves (25°C Ambient Temperature Unless Otherwise Noted)

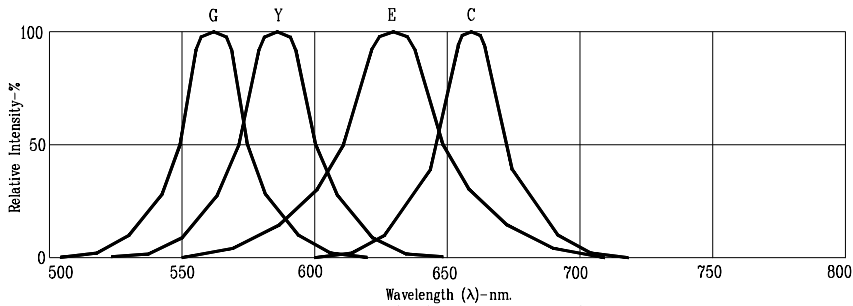


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

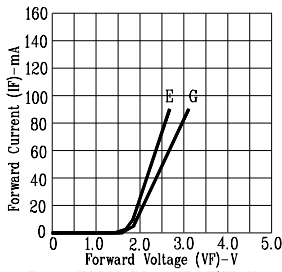


Fig2. FORWARD CURRENT VS. FORWARD VOLTAGE

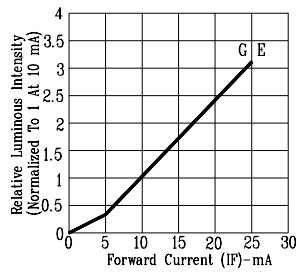


Fig3. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

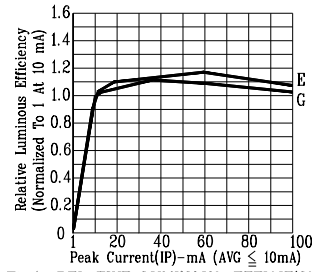


Fig4. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

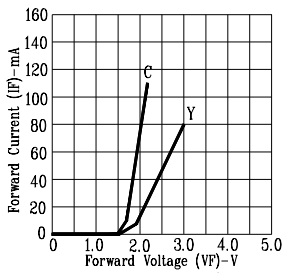


Fig5. FORWARD CURRENT VS. FORWARD VOLTAGE

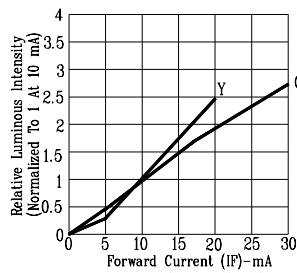


Fig6. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

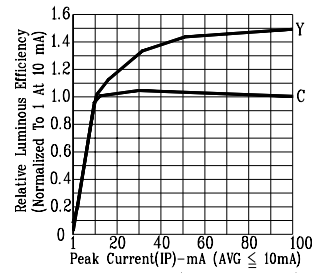


Fig7. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT

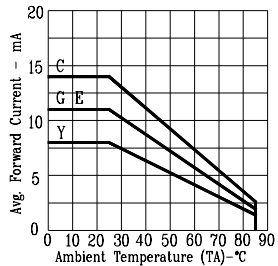


Fig8. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

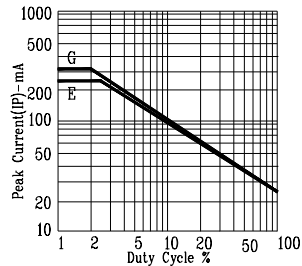


Fig9. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

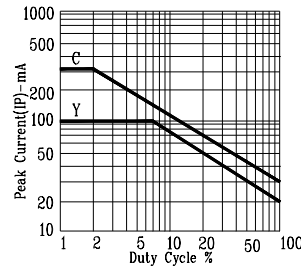


Fig10. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: G=GREEN E=RED ORANGE C=AlGaAs RED Y=YELLOW (REFRESH RATE 1KHz)